# High Current Surface Mount PNP Silicon Switching Transistor for Load Management in Portable Applications

### **Features**

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

# **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	-30	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	-50	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	-1.0	Adc
Collector Current - Peak	I <sub>CM</sub>	-2.0	Α

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	310 2.5	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	403	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	710 5.7	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	176	°C/W
Total Device Dissipation (Ref. Figure 8) (Single Pulse < 10 sec.)	P <sub>Dsingle</sub>	575	mW
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

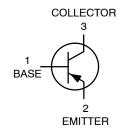
- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 X 1.0 inch Pad



# ON Semiconductor®

http://onsemi.com

# 30 VOLTS, 2.0 AMPS PNP TRANSISTORS





SOT-23 (TO-236) CASE 318 STYLE 6

# **MARKING DIAGRAM**



G3 = Device Code
M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

# **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT589LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

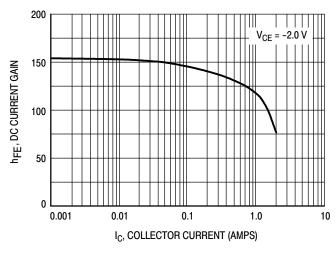
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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# $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}\text{C unless otherwise noted})$

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage ( $I_C = -10$ mAdc, $I_B = 0$ )	V <sub>(BR)CEO</sub>	-30	_	Vdc
Collector – Base Breakdown Voltage $(I_C = -0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)CBO</sub>	-50	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = -0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	-5.0	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -30 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-0.1	μAdc
Collector-Emitter Cutoff Current (V <sub>CES</sub> = -30 Vdc)	I <sub>CES</sub>	-	-0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = -4.0 Vdc)	I <sub>EBO</sub>	-	-0.1	μAdc
ON CHARACTERISTICS	<u> </u>			
DC Current Gain (Note 3) (Figure 1) $ \begin{array}{l} (I_C = -1.0 \text{ mA}, V_{CE} = -2.0 \text{ V}) \\ (I_C = -500 \text{ mA}, V_{CE} = -2.0 \text{ V}) \\ (I_C = -500 \text{ mA}, V_{CE} = -2.0 \text{ V}) \\ (I_C = -1.0 \text{ A}, V_{CE} = -2.0 \text{ V}) \\ (I_C = 2.0 \text{ A}, V_{CE} = -2.0 \text{ V}) \end{array} $	h <sub>FE</sub>	100 100 80 40	- 300 - -	-
Collector – Emitter Saturation Voltage (Note 3) (Figure 3) $ \begin{array}{l} (I_C=-0.5~A,~I_B=-0.05~A)\\ (I_C=-1.0~A,~I_B=0.1~A)\\ (I_C=-2.0~A,~I_B=-0.2~A) \end{array} $	V <sub>CE(sat)</sub>	- - -	-0.25 -0.30 -0.65	V
Base – Emitter Saturation Voltage (Note 3) (Figure 2) (I <sub>C</sub> = -1.0 A, I <sub>B</sub> = -0.1 A)	V <sub>BE(sat)</sub>	-	-1.2	V
Base – Emitter Turn–on Voltage (Note 3) $(I_C = -1.0 \text{ A, } V_{CE} = -2.0 \text{ V})$	V <sub>BE(on)</sub>	-	-1.1	V
Cutoff Frequency ( $I_C = -100 \text{ mA}$ , $V_{CE} = -5.0 \text{ V}$ , $f = 100 \text{ MHz}$ )	f <sub>T</sub>	100	_	MHz
Output Capacitance (f = 1.0 MHz)	Cobo	-	15	pF

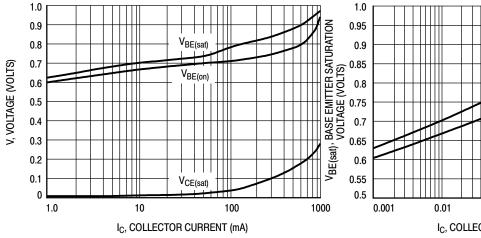
<sup>3.</sup> Pulsed Condition: Pulse Width = 300 msec, Duty Cycle ≤ 2%



230 V<sub>CE</sub> = -1.0 V 210 125°C 190 hFE, DC CURRENT GAIN 5 01 05 05 05 55 25°C 90 -55°C 70 50 1.0 10 100 1000 IC, COLLECTOR CURRENT (mA)

Figure 1. DC Current Gain versus Collector Current

Figure 2. DC Current Gain versus Collector Current



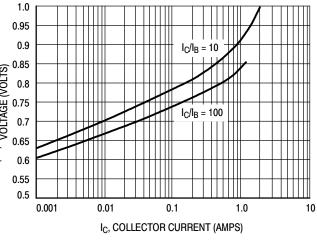
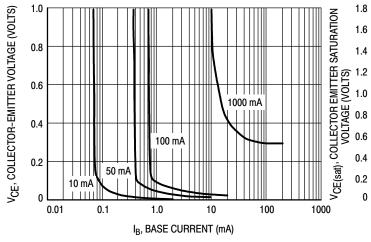


Figure 3. "On" Voltages

Figure 4. Base Emitter Saturation Voltage versus Collector Current



1.8
1.6
1.4
1.2
1.0
1.0
0.8
0.4
0.2
0
0.001
0.01
0.1
1.0
10
1c/l<sub>B</sub> = 100
1c/l<sub>B</sub> = 10

Figure 5. Collector Emitter Saturation Voltage versus Collector Current

Figure 6. Collector Emitter Saturation Voltage versus Collector Current

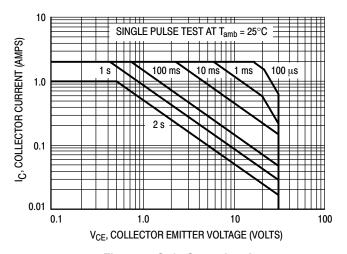


Figure 7. Safe Operating Area

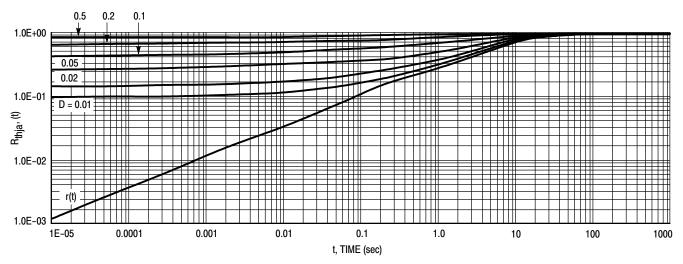
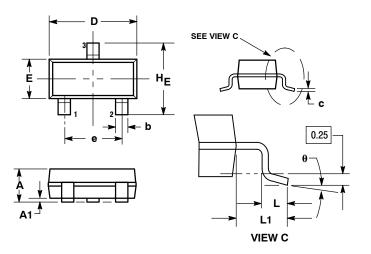


Figure 8. Normalized Thermal Response

# PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 



### NOTES

- DIMENSIONING AND TOLERANCING PER

- ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

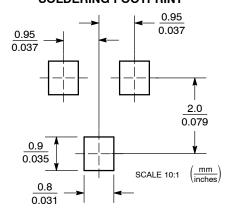
  3. MAXIMUM LEAD THICKNESS INCLUDES
  LEAD FINISH THICKNESS. MINIMUM LEAD
  THICKNESS IS THE MINIMUM THICKNESS OF
  PACE MATERIAL BASE MATERIAL.
- 4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
He	2 10	2 40	2 64	0.083	0.094	0.104

## STYLE 6:

- PIN 1. BASE 2. EMITTER
  - COLLECTOR

# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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